

# ZXTP08400BFF 400V, SOT23F, PNP medium power high voltage transistor

## Summary;

 $BV_{CEO} > -400V$ 

 $BV_{ECO} > -6V$ 

 $I_{C(cont)} = -0.2A$ 

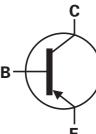
V<sub>CE(sat)</sub> < 220mV @ 100mA

 $P_{D} = 1.5W$ 

Complementary part number ZXTN08400BFF

## **Description**

This PNP transistor has been designed for applications requiring high blocking voltage. The SOT23F package is pin compatible with the industry standard SOT23 footprint but offers lower profile and higher dissipation for applications where power density is of utmost importance.

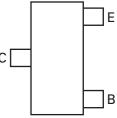


### **Features**

- · High voltage
- · Low saturation voltage

## **Applications**

· Telecoms switching

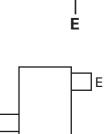


## **Ordering information**

Device	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP08400BFFTA	7	8	3000

## **Device marking**

1D6



Pinout - top view

## **Absolute maximum ratings**

Parameter	Symbol	Limit	Unit
Collector-base voltage	V <sub>CBO</sub>	-400	V
Collector-emitter voltage	V <sub>CEO</sub>	-400	V
Emitter-collector voltage (reverse blocking)	V <sub>ECO</sub>	-6	V
Emitter-base voltage	V <sub>EBO</sub>	-7	V
Continuous collector current(c)	I <sub>C</sub>	-0.2	Α
Peak pulse current	I <sub>CM</sub>	-1	Α
Base current	I <sub>B</sub>	-0.2	Α
Power dissipation at T <sub>amb</sub> =25°C <sup>(a)</sup>		0.84	W
Linear derating factor	P <sub>D</sub>	6.72	mW/°C
Power dissipation at T <sub>amb</sub> =25°C <sup>(b)</sup>		1.34	W
Linear derating factor	P <sub>D</sub>	10.72	mW/°C
Power dissipation at T <sub>amb</sub> =25°C <sup>(c)</sup>		1.50	W
Linear derating factor	$P_{D}$	12.0	mW/°C
Power dissipation at T <sub>amb</sub> =25°C <sup>(d)</sup>		2.0	W
Linear derating factor	P <sub>D</sub>	16.0	mW/°C
Operating and storage temperature range	T <sub>j</sub> , T <sub>stg</sub>	-55 to 150	°C

### Thermal resistance

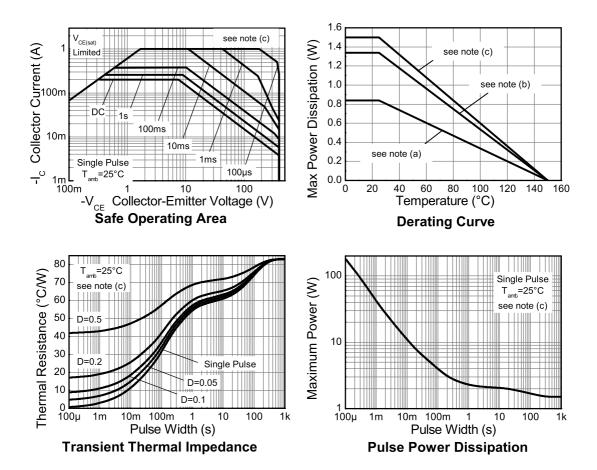
Parameter	Symbol	Limit	Unit	
Junction to ambient <sup>(a)</sup>	$R_{\Theta JA}$	149	°C/W	
Junction to ambient <sup>(b)</sup>	$R_{\Theta JA}$	93	°C/W	
Junction to ambient <sup>(c)</sup>	$R_{\Theta JA}$	83	°C/W	
Junction to ambient <sup>(d)</sup>	$R_{\Theta JA}$	60	°C/W	

### NOTES:

<sup>(</sup>a) For a device surface mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

<sup>(</sup>b) Mounted on 25mm x 25mm x 1.6mm FR4 PCB with a high coverage of single sided 2 oz copper in still air conditions. (c) Mounted on 50mm x 50mm x 1.6mm FR4 PCB with a high coverage of single sided 2 oz copper in still air conditions. (d) As (c) above measured at t<5secs.

### **Characteristics**



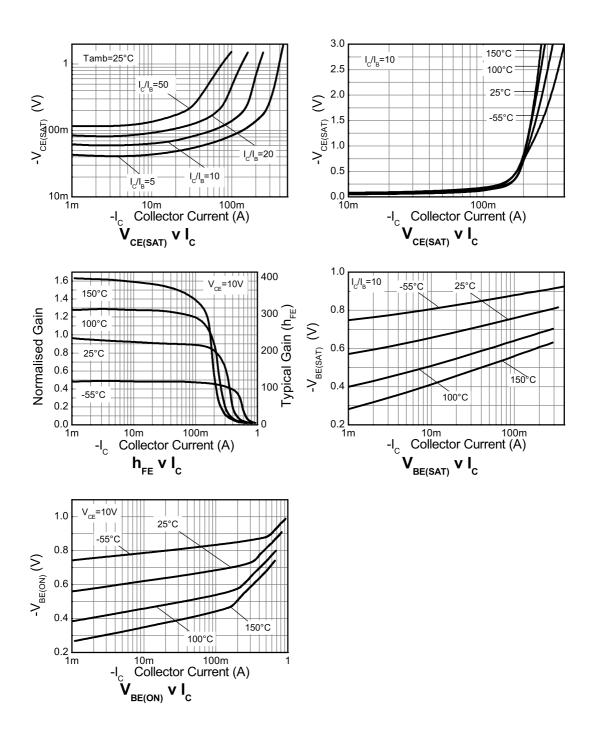
# Electrical characteristics (at T<sub>amb</sub> = 25°C unless otherwise stated)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV <sub>CBO</sub>	-400	-500		V	$I_C = -100 \mu A$
Collector-emitter breakdown voltage (base open)	BV <sub>CEO</sub>	-400	-480		V	I <sub>C</sub> = -10mA <sup>(*)</sup>
Emitter-base breakdown voltage	BV <sub>EBO</sub>	-7	-8.1		V	$I_E = -100 \mu A$
Emitter-collector breakdown voltage (reverse blocking)	BV <sub>ECX</sub>	-6	-8.2		V	$I_E = -100 \mu A$ , $R_{BC} < 1 k \Omega$ or $0.25 V > V_{BC} > -0.25 V$
Emitter-collector breakdown voltage (base open)	BV <sub>ECO</sub>	-6	-8.6		V	$I_E = -100 \mu A$ ,
Collector-base cut-off current	I <sub>CBO</sub>		<-1	-50	nA	V <sub>CB</sub> = -320V
				-20	μΑ	$V_{CB} = -320V, T_{amb} = 100^{\circ}C$
Emitter-base cut-off current	I <sub>EBO</sub>		<-1	-50	nA	V <sub>EB</sub> = -5.6V
Collector-emitter saturation	V <sub>CE(sat)</sub>		-10	-145	mV	$I_C = -20 \text{mA}, I_B = -1 \text{mA}^{(*)}$
voltage			-95	-125	mV	$I_C = -50 \text{mA}, I_B = -5 \text{mA}^{(*)}$
			-140	-220	mV	$I_C = -100 \text{mA}, I_B = -10 \text{mA}^{(*)}$
			-140	-190	mV	$I_C = -200 \text{mA}, I_B = -40 \text{mA}^{(*)}$
Base-emitter saturation voltage	V <sub>BE(sat)</sub>		-810	-900	mV	$I_C = -200 \text{mA}, I_B = -40 \text{mA}^{(*)}$
Base-emitter turn-on voltage	V <sub>BE(on)</sub>		-705	-800	mV	$I_C = -200 \text{mA}, V_{CE} = -10 V^{(*)}$
Static forward current	h <sub>FE</sub>	100	220			$I_C = -1mA, V_{CE} = -5V^{(*)}$
transfer ratio		100	200	300		$I_C = -50 \text{mA}, V_{CE} = -5V^{(*)}$
		100	200			$I_C = -200 \text{mA}, V_{CE} = -10 V^{(*)}$
Transition frequency	f <sub>T</sub>	50	70		MHz	I <sub>C</sub> = -20mA, V <sub>CE</sub> = -20V f = 20MHz
Output capacitance	C <sub>obo</sub>		12.9	20	pF	V <sub>CB</sub> = -20V, f = 1MHz <sup>(*)</sup>
Delay time	t <sub>d</sub>		95		ns	V <sub>CC</sub> = -100V.
Rise time	t <sub>r</sub>		73.8		ns	$I_{C} = -100 \text{mA},$
Storage time	t <sub>s</sub>		1790		ns	I <sub>B1</sub> = 10mA, I <sub>B2</sub> = -20mA.
Fall time	t <sub>f</sub>		153.8		ns	

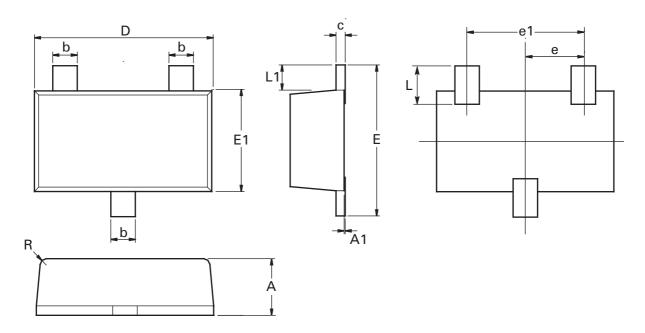
### NOTES:

(\*) Measured under pulsed conditions. Pulse width  ${\leq}300\mu s;$  duty cycle  ${\leq}2\%.$ 

## **Typical characteristics**



## Package outline - SOT23F



Dim.	Millimeters		Inches		Dim.	im. Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
Α	0.80	1.00	0.0315	0.0394	Е	2.30	2.50	0.0906	0.0984
A1	0.00	0.10	0.00	0.0043	E1	1.50	1.70	0.0590	0.0669
b	0.35	0.45	0.0153	0.0161	L	0.48	0.68	0.0189	0.0268
С	0.10	0.20	0.0043	0.0079	L1	0.30	0.50	0.0153	0.0161
D	2.80	3.00	0.1102	0.1181	R	0.05	0.15	0.0019	0.0059
е	0.95	ref	0.037	74 ref	0	0°	12°	0°	12°
e1	1.80	2.00	0.0709	0.0787	-	-	-	-	-

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

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